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# KA258/KA258A, KA358/KA358A, KA2904

# **Dual Operational Amplifier**

#### **Features**

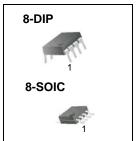
- Internally Frequency Compensated for Unity Gain
- Large DC Voltage Gain: 100dB
- Wide Power Supply Range: KA258/KA258A, KA358/KA358A: 3V ~ 32V (or ±1.5V~ 16V)

 $KA2904 : 3V \sim 26V \text{ (or } \pm 1.5V \sim 13V)$ 

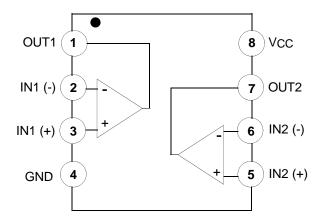
- Input Common Mode Voltage Range Includes Ground
- Large Output Voltage Swing: 0V DC to Vcc 1.5V DC
- Power Drain Suitable for Battery Operation.

### **Description**

The KA258 series consist of two independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltage. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. Application areas include transducer amplifier, DC gain blocks and all the conventional OP-AMP circuits which now can be easily implemented in single power supply systems.

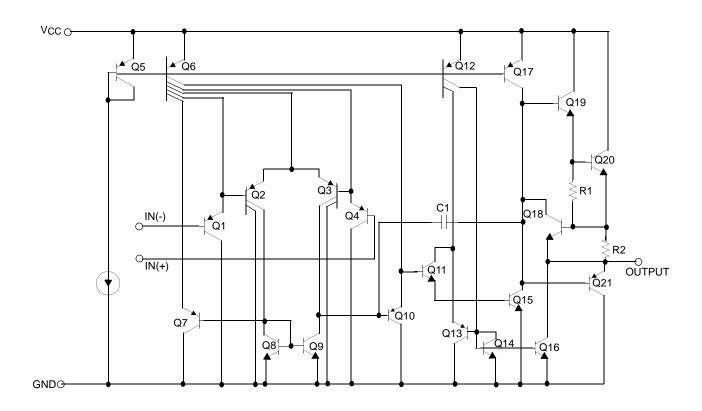


### Internal Block Diagram



### **Schematic Diagram**

(One section only)



## **Absolute Maximum Ratings**

Parameter	Symbol	KA258/KA258A	KA358/KA358A	KA2904	Unit
Supply Voltage	Vcc	±16 or 32	±16 or 32	±13 or 26	V
Differential Input Voltage	VI(DIFF)	32	32	26	V
Input Voltage	Vı	-0.3 to +32	-0.3 to +32	-0.3 to +26	V
Output Short Circuit to GND VCC≤15V, TA = 25°C(One Amp)	-	Continuous	Continuous	Continuous	-
Operating Temperature Range	TOPR	-25 ~ +85	0 ~ +70	-40 ~ +85	°C
Maximum Junction Temperature	T <sub>J</sub> (MAX)	+150	+150	+150	°C
Storage Temperature Range	TSTG	-65 ~ +150	-65 ~ +150	-65 ~ +150	°C

### **Electrical Characteristics**

(VCC = 5.0V, VEE = GND,  $T_A = 25$ °C, unless otherwise specified)

Danamatan	Comple ed				KA258			KA358			KA2904			
Parameter	Symbol			Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit	
Input Offset Voltage	VIO	VCM = 0V to VO(P) = 1.4V		-	2.9	5.0	-	2.9	7.0	-	2.9	7.0	mV	
Input Offset Current	lio	-		-	3	30	-	5	50	-	5	50	nA	
Input Bias Current	IBIAS	-		-	45	150	-	45	250	-	45	250	nA	
Input Voltage Range	VI(R)	VCC = 30V (KA2904, VC	cc = 26V)	0	-	VCC -1.5	0	-	VCC -1.5	0	-	VCC -1.5	V	
Supply	Icc	RL = ∞, VCC (KA2904, VC		-	0.8	2.0	-	0.8	2.0	-	8.0	2.0	mA	
Current	100	$RL = \infty$ , $VCC$	= 5V	-	0.5	1.2	-	0.5	1.2	-	0.5	1.2	mA	
Large Signal Voltage Gain	Gv	$V_{CC} = 15V$ , $R_L = 2k\Omega$ $V_{O(P)} = 1V$ to $11V$		50	100	-	25	100	-	25	100	-	V/mV	
Output	VO(H)	VCC = 30V	$RL = 2k\Omega$	26	-	-	26	-	-	22	-	-	V	
Voltage Swing	V O(11)	(VCC = 26V for KA2904)	$R_L = 10k\Omega$	27	28	-	27	28	-	23	24	-	V	
Swillig	VO(L)	Vcc = 5V, R	L = 10kΩ	-	5	20	-	5	20		5	20	mV	
Common- Mode Rejection Ratio	CMRR	_		70	85	-	65	80	-	50	80	-	dB	
Power Supply Rejection Ratio	PSRR	-		65	100	-	65	100	-	50	100	-	dB	
Channel Separation	CS	f = 1kHz to 2 (Note1)	0kHz	-	120	-	-	120	-	-	120	-	dB	
Short Circuit to GND	Isc	-		-	40	60	-	40	60	-	40	60	mA	
	ISOURCE	V <sub>I(+)</sub> = 1V, V <sub>I(-)</sub> = 0V V <sub>CC</sub> = 15V, V <sub>O(P)</sub> = 2V		20	30	-	20	30	•	20	30	ı	mA	
Output Current	VI(+) = 0V, VI(-) = 1V VCC = 15V, VO(P) = 2V		10	15	-	10	15	-	10	15	-	mA		
333	ISINK	V <sub>I(+)</sub> = 0V, V <sub>I(-)</sub> = 1V V <sub>CC</sub> = 15V, V <sub>O(P)</sub> = 200mV		12	100	-	12	100	-	-	-	-	μΑ	
Differential Input Voltage	VI(DIFF)	-		-	-	Vcc	-	-	Vcc	-	-	Vcc	V	

#### Note:

<sup>1.</sup> This parameter, although guaranteed, is not 100% tested in production.

### **Electrical Characteristics** (Continued)

(VCC = 5.0V, VEE = GND, unless otherwise specified) The following specification apply over the range of -25°C  $\leq$  TA  $\leq$  +85°C for the KA258; and the 0 °C  $\leq$  TA  $\leq$  +70°C for the KA358; and the -40°C  $\leq$  TA  $\leq$  +85°C for the KA2904

Danamatan	Or made al	Conditions		KA258			KA358				11:4:4		
Parameter	Symbol	Condi	Conditions		Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO	$V_{CM} = 0V \text{ to } V_{O(P)} = 1.4V,$		-	-	7.0	-	ı	9.0	ı	-	10.0	mV
Input Offset Voltage Drift	ΔVΙΟ/ΔΤ	$Rs = 0\Omega$		-	7.0	-	-	7.0	-	-	7.0	-	μV/°C
Input Offset Current	liO	-		-	-	100	-	-	150	-	45	200	nA
Input Offset Current Drift	ΔΙ <sub>ΙΟ</sub> /ΔΤ	-		-	10	-	-	10	-	-	10	-	pA/°C
Input Bias Current	IBIAS	-		-	40	300	-	40	500	-	40	500	nA
Input Voltage Range	VI(R)	V <sub>CC</sub> = 30V (KA2904,V <sub>CC</sub> = 26V)		0	-	Vcc -2.0	0	-	VCC -2.0	0	-	VCC -2.0	٧
Large Signal Voltage Gain	G∨	$V_{CC}$ = 15V, R <sub>L</sub> =2.0kΩ $V_{O(P)}$ = 1V to 11V		25	-	-	15	-	-	15	-	-	V/mV
Output		VCC = 30V	$R_L = 2k\Omega$	26	-	-	26	-	-	22	-	-	V
Voltage Swing	VO(H)	(VCC = 26V for KA2904)	$R_L = 10k\Omega$	27	28	-	27	28	-	23	24	-	V
Swirig	VO(L)	$VCC = 5V, RL=10k\Omega$		-	5	20	-	5	20	-	5	20	mV
Output	ISOURCE	$V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V, V_{O(P)} = 2V$		10	30	-	10	30	-	10	30	-	mA
Current	ISINK	VI(+) = 0V, VI(-) = 1V VCC = 15V, VO(P) = 2V		5	8	-	5	9	-	5	9	-	mA
Differential Input Voltage	VI(DIFF)	-		-	-	Vcc	-	-	Vcc	-	-	Vcc	V

### **Electrical Characteristics** (Continued)

(VCC = 5.0V, VEE = GND, TA = 25°C, unless otherwise specified)

Davamatar Compl		Conditions			<b>KA258</b>	BA	ŀ	Unit		
Parameter	Symbol	Conditio	Min.	Тур.	Max.	MIn.	Тур.	Max.	Onne	
Input Offset Voltage	VIO	VCM = 0V to VCC - VO(P) = 1.4V, RS =		-	1.0	3.0	-	2.0	3.0	mV
Input Offset Current	lio	-		-	2	15	-	5	30	nA
Input Bias Current	IBIAS	-		-	40	80	-	45	100	nA
Input Voltage Range	VI(R)	Vcc = 30V		0	-	VCC -1.5	0	-	VCC -1.5	V
Cupply Current	loo	RL = ∞, VCC = 30V		-	0.8	2.0	-	8.0	2.0	mA
Supply Current	ICC	RL = ∞, Vcc = 5V		-	0.5	1.2	-	0.5	1.2	mA
Large Signal Voltage Gain	G∨	$V_{CC}$ = 15V, $R_L$ =2k $\Omega$ $V_O$ = 1V to 11V		50	100	-	25	100	-	V/mV
	Voн	VCC = 30V	$R_L = 2k\Omega$	26	-	-	26		-	V
Output Voltage Swing			R <sub>L</sub> = 10kΩ	27	28	-	27	28	-	V
Owing	VO(L)	Vcc = 5V, R <sub>L</sub> =10ks	Ω	-	5	20	-	5	20	mV
Common-Mode Rejection Ratio	CMRR	-	70	85	-	65	85	-	dB	
Power Supply Rejection Ratio	PSRR	-		65	100	-	65	100	-	dB
Channel Separation	CS	f = 1kHz to $20kHz$ (	(Note1)	-	120	-	-	120	-	dB
Short Circuit to GND	Isc	-		-	40	60	-	40	60	mA
	ISOURCE	V <sub>I</sub> (+) = 1V, V <sub>I</sub> (-) = 0V V <sub>CC</sub> = 15V, V <sub>O</sub> (P) = 2V		20	30	-	20	30	-	mA
Output Current	lowur	V <sub>I</sub> (+) = 1V, V <sub>I</sub> (-) = 0 VCC = 15V, VO(P)	10	15	-	10	15	-	mA	
	Isink	Vin(+) = 0V, Vin (-) = 1V VO(P) = 200mV		12	100	-	12	100	-	μА
Differential Input Voltage	VI(DIFF)	-	-	-	Vcc	-	-	Vcc	V	

#### Note:

<sup>1.</sup> This parameter, although guaranteed, is not 100% tested in production.

### **Electrical Characteristics** (Continued)

(VCC = 5.0V, VEE = GND, unless otherwise specified) The following specification apply over the range of -25°C  $\leq$  TA  $\leq$  +85°C for the KA258A; and the 0°C  $\leq$  TA  $\leq$  +70°C for the KA358A

Davamatar	Cumbal	Come	K	(A258	Α	ŀ	11			
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO	$V_{CM} = 0V_{CM}$ $V_{O(P)} = 1.4V_{CM}$		-	-	4.0	-	-	5.0	mV
Input Offset Voltage Drift	ΔV10/ΔΤ		-	-	7.0	15	-	7.0	20	μV/°C
Input Offset Current	ΙΙΟ		-	-	-	30	-	-	75	nA
Input Offset Current Drift	ΔΙΙΟ/ΔΤ		-	-	10	200	-	10	300	pA/°C
Input Bias Current	IBIAS	-		-	40	100	-	40	200	nA
Input Common-Mode Voltage Range	VI(R)	VCC = 30V		0	-	VCC -2.0	0	-	VCC -2.0	V
	V = 0.0		$R_L = 2k\Omega$	26	-	-	26	-	-	V
Output Voltage Swing	VO(H)	VCC = 30V	RL = 10kΩ	27	28	-	27	28	-	V
	VO(L)	VCC = 5V, R	L=10kΩ	-	5	20	-	5	20	mV
Large Signal Voltage Gain	G∨	$V_{CC}$ = 15V, R <sub>L</sub> =2.0kΩ $V_{O(P)}$ = 1V to 11V		25	-	-	15	-	-	V/mV
Output Current	ISOURCE $VI(+) = 1V, VI(-) = 0V$ VCC = 15V, VO(P) = 2V			10	30	-	10	30	-	mA
Output Current	ISINK	V <sub>I(+)</sub> = 1V, V <sub>I(-)</sub> = 0V VCC = 15V, V <sub>O(P)</sub> = 2V		5	9	-	5	9	-	mA
Differential Input Voltage	VI(DIFF)	-		-	-	Vcc	-	-	Vcc	V

### **Typical Performance Characteristics**

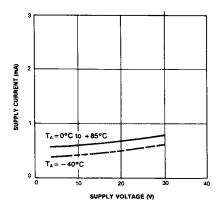


Figure 1. Supply Current vs Supply Voltage

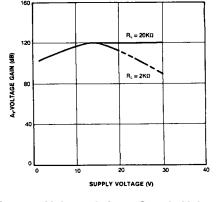


Figure 2. Voltage Gain vs Supply Voltage

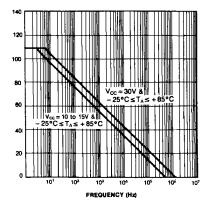


Figure 3. Open Loop Frequency Response

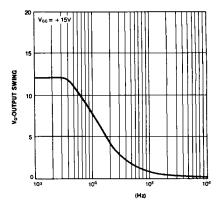


Figure 4. Large Signal Output Swing vs Frequency

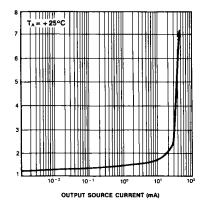


Figure 5. Output Characteristics vs Current Sourcing

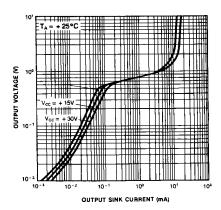


Figure 6. Output Characteristics vs Current Sinking

### **Typical Performance Characteristics** (Continued)

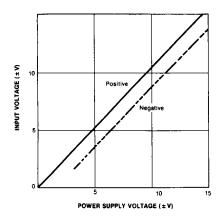


Figure 7. Input Voltage Range vs Supply Voltage

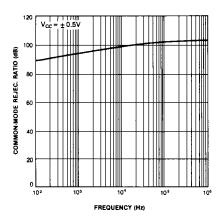


Figure 8. Common-Mode Rejection Ratio

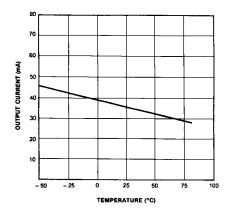


Figure 9. Output Current vs Temperature (Current Limiting)

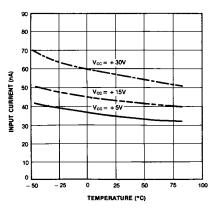


Figure 10. Input Current vs Temperature

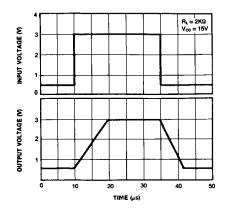


Figure 11. Voltage Follower Pulse Response

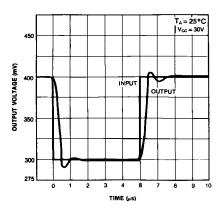
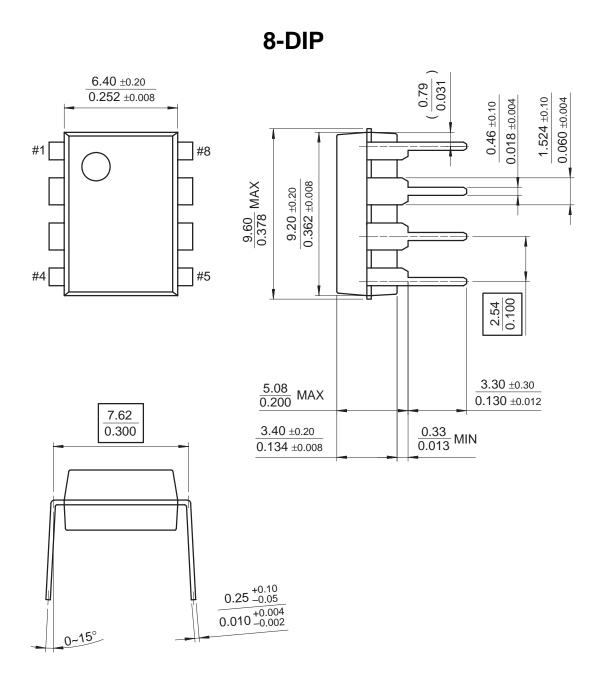


Figure 12. Voltage Follower Pulse Response (Small Signal)

### **Mechanical Dimensions**

### **Package**

#### **Dimensions in millimeters**

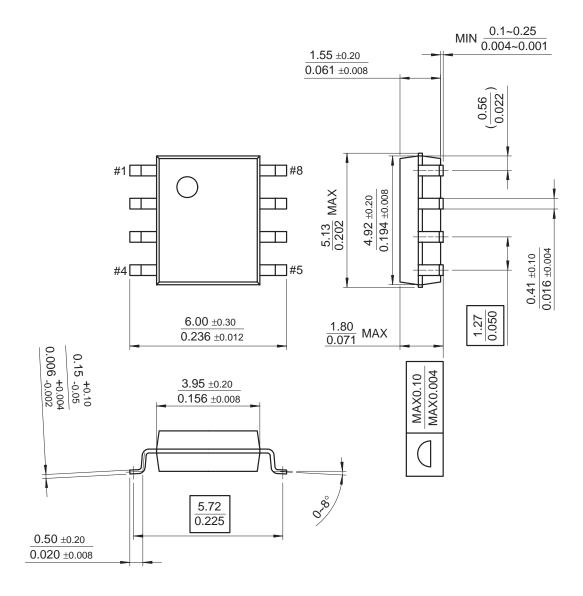


### **Mechanical Dimensions** (Continued)

### **Package**

#### **Dimensions in millimeters**

# 8-SOIC



### **Ordering Information**

Product Number	Package	Operating Temperature
KA358	8-DIP	
KA358A	0-011	0 ~ +70°C
KA358D	8-SOIC	0 ~ +70 C
KA358AD	0-3010	
KA258D	8-SOIC	-25 ∼ +85°C
KA258AD	0-3010	-25 ~ <del>1</del> 65 C
KA2904	8-DIP	-40 ∼ +85°C
KA2904D	8-SOIC	-40 ~ <del>1</del> 00 C

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